

IN THE CLAIMS:

This listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Previously presented) A light-emitting element comprising:

an anode;

a first layer formed over the anode and containing a light-emitting material;

a second layer formed over and being in direct contact with the first layer and containing an organic compound, an electron-supplying material and a first metal oxide;

a third layer formed over and being in direct contact with the second layer, the third layer including a transparent conductive film;

a fourth layer formed over and being in contact with the third layer and containing a hole-transporting medium; and

a cathode formed over and being in direct contact with the fourth layer, the cathode containing a metal,

wherein the transparent conductive film comprises a material selected from the group consisting of tin oxide, indium oxide, zinc oxide, zinc oxide containing gallium, and molybdenum oxide.

2. (Canceled)

3-12. (Canceled)

13. (Previously Presented) The light-emitting element according to claim 1, wherein the

fourth layer contains an organic compound and is doped with an electron-accepting material.

14. (Previously Presented) The light-emitting element according to claim 13, wherein the organic compound is a hole-transporting material.

15. (Original) The light-emitting element according to claim 14, wherein the hole-transporting material is an organic compound having an aromatic amine skeleton.

16-19 (Canceled)

20. (Previously presented) A light-emitting element comprising:

an anode;

a first layer formed over the anode and containing a light-emitting material;

a second layer formed over and being in direct contact with the first layer and containing an organic compound, an electron-supplying material and a first metal oxide;

a third layer formed over and being in direct contact with the second layer, the third layer including a transparent conductive film comprising a metal;

a fourth layer formed over and being in contact with the third layer and containing a hole-transporting medium and an electron-accepting material; and

a cathode formed over and being in direct contact with the fourth layer, the cathode containing a metal.

21 (Canceled).

22. (Previously Presented) A light-emitting element comprising:

- an anode;
- a first layer formed over the anode and containing a light-emitting material;
- a second layer formed over and being in direct contact with the first layer and containing an organic compound, an electron-supplying material and a first metal oxide;
- a third layer formed over and being in direct contact with the second layer, the third layer including a transparent conductive film;
- a fourth layer formed over and being in contact with the third layer and containing a hole-transporting medium and an electron-accepting material; and
- a cathode formed over and being in direct contact with the fourth layer, the cathode containing a metal,

wherein the transparent conductive film comprises a material selected from the group consisting of tin oxide, indium oxide, zinc oxide, zinc oxide containing gallium, and molybdenum oxide.

23. (Previously presented) The light-emitting element according to any one of claims 1, 20, and 22, wherein the first metal oxide is one selected from the group consisting of molybdenum oxide, vanadium oxide, rhenium oxide, zinc oxide, tin oxide, and titanium oxide.

24. (Previously presented) The light-emitting element according to any one of claims 13, 20 and 22, wherein the electron-accepting material is a second metal oxide.

25. (Previously presented) The light-emitting element according to any one of claims 13, 20 and 22, wherein the electron-accepting material is selected from any one or more of molybdenum oxide, vanadium oxide, and rhenium oxide.

26. (Previously presented) The light-emitting element according to any one of claims 13, 20 and 22, wherein the electron-accepting material is molybdenum oxide.

27. (Previously presented) The light-emitting element according to any one of claims 1, 20, and 22, wherein the first layer is formed in multilayer structure.

28. (Previously presented) The light-emitting element according to any one of claims 1, 20, and 22, wherein the transparent conductive film is thin enough to have light-transmitting properties.

29. (Previously presented) The light-emitting element according to any one of claims 1, 20, and 22, wherein the organic compound contained in the second layer is an electron-transporting organic compound.

30. (Currently Amended) The light-emitting element according to any one of claims 1, 20, and 22, wherein the organic compound contained in the second layer is a metal complex having a ligand including $[\square]$ π -conjugated skeleton.

31. (Previously presented) The light-emitting element according to any one of claims 1, 20, and 22, wherein the electron-supplying material is an alkaline metal, an alkaline earth metal, or a

rare-earth metal.

32. (Previously presented) The light-emitting element according to any one of claims 1, 20, and 22, wherein the electron-supplying material is a metal selected from any one or more of Li, Cs, Mg, Ca, Sr, Ba, Er, and Yb.

33. (Currently Amended) The light-emitting element according to any one of claims 1, 20, and 22, wherein the anode is formed with indium tin oxide, indium tin oxide containing silicon oxide, zinc oxide, indium oxide containing zinc oxide by 2% to 20%, zinc oxide containing gallium, tin oxide, or indium oxide.

34. (Previously presented) An electronic device of which display portion is equipped with the light-emitting element according to any one of claims 1, 20, and 22.